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Structural characterization of HPM-7, a more ordered than expected germanosilicate zeolite†

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HPM-7, a germanosilicate synthesized using long imidazolium-based dications with two different linkers, is shown to possess the POS topology, although disorder may exist but it is very difficult to discern. First, three simple ordered polymorphs (POS-A to POS-C) with very similar energies and structural motifs could give rise to intergrowths that would be very difficult to recognize by powder X-ray diffraction, according to DIFFaX simulations. Another four structures (POS-D to POS-G) can be derived from POS by changing the orientation of two single four rings within the structure, possibly providing an additional source of disorder. While 3D EDT strongly suggests that HPM-7 basically possesses the POS-A (i.e. POS) topology, a detailed HR-STEM study demonstrates the rare existence of some disorder compatible with the polymorph POS-D. The general avoidance of polymorphs with very similar structural motifs and comparable energies points to a rather specific structure-direction by the organic dications used.

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1. Introduction

The broad applicability of synthetic zeolites in adsorption, ion-exchange, catalysis and other processes relies on the wide variability of their properties, which is in turn related to the ample diversity of structures and chemical compositions that zeolites possess. This ample diversity is the consequence of a large synthesis effort carried out over the last almost eight decades. Central to rationalizing both the synthesis and applications of a zeolite is the detailed knowledge of its crystalline structure, necessary to determine both structure-synthesis and structure-application relationships. However, the structure determination of zeolites is typically hindered by the difficulty of synthesizing crystals large enough for single crystal diffrac-

tion, by their typically large unit cells, by their frequently low crystallinity and, frequently, by the existence of disorder. Zeolites may show several types of structural disorder, including intergrowth of polymorphs, disordered distribution of heteroatoms over the available crystallographic sites, the presence of connectivity defects and disordered arrangement of guests. Despite the recent progress in characterization and analysis techniques, 4,5 the accurate and detailed structural determination of zeolites is still far from being a routine endeavor.

Here we show our structural characterization of HPM-7, a large pore germanosilicate recently synthesized in our group by using an imidazolium-based long dication in the presence of fluoride. While in our previous work we recognized that HPM-7 likely possessed the POS topology, doubts arised concerning the possible existence of several forms of disorder, which we discuss here. This work emphasizes on one hand the difficulty of proving/disproving disorder in certain systems consisting of much similar polymorphs. On the other hand, it shows that the structure-direction may favour the formation of a single polymorph by preventing the extensive formation of closely related structures, even when they have similar or even smaller energies.

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Experimental

2.1 Synthesis of organic structure directing agents and zeolites

The SDAs used in this work are octamethylene-bis-(2,3-dimethylimidazolium), denoted as 8BDMI (Fig. 1) and deca-

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[†] Electronic supplementary information (ESI) available: Fig. S1, a Rietveld plot of the as-made HPM-7 (λ = 0.56383 Å); Fig. S2, stacking faults of POS-A and POS-B along a unique direction ([1–10] o [110]); Fig. S3, the simulated XRD patterns for POS-C intergrown with itself with or without a 90° rotation; Fig. S4, different cutting planes from 3D-EDT data; Table S1, 29 independent 3D-EDT datasets; Fig. S5, C_s -corrected STEM ADF analysis of HPM-7 along the [001] zone axis. See POI: 10.1039/D0DT00818D

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Fig. 1 The decamethylene-bis-(2,3-dimethylimidazolium) (10BDMI, top) and octamethylene-bis-(2,3-dimethylimidazolium) (8BDMI, bottom) dications used to synthesize HPM-7, depicted using the open code JChemPaint.8

methylene-bis-(2,3-dimethylimidazolium), denoted 10BDMI. This type of dication cannot be described as diquaternary ammonium compounds, as wrongly expressed very frequently in the literature, because none of the N is actually a quaternary ammonium (there are only three substituents at the nitrogen atoms).⁷ The dications were synthesized as described in our previous work,6 where the zeolite synthesis protocol was also described.

2.2 Characterization

Routine powder X-ray diffraction (PXRD) data were obtained on a Bruker D8 Advance diffractometer using Cu Kα radiation $(\lambda = 1.5418 \text{ Å})$. Synchrotron powder X-ray diffraction (SPXRD) was performed in Debye-Scherrer geometry (0.8 mm capillary) using the SpLine BM25A at the ESRF, Grenoble ($\lambda = 0.56383 \text{ Å}$). Rietveld refinement was carried out using GSAS9 under the EXPGUI interface. 10 Routine field emission scanning electron micrographs (FE-SEM) were collected using a Philips XL30 S-FEG. HRTEM images and 3D Electron Diffraction Tomography, 3D-EDT, data were collected in a similar way to that reported for HPM-8 in our previous work.⁶

2.3 Computational methods

The relative stability of the different polymorphs derived from the POS framework (see below) was studied by DFT, using the CASTEP code, 11 the PBE generalized gradient approximation, 12 and plane-waves as the basis set (with a cut-off of 571.4 eV). The energies are expressed relative to that of quartz, in kcal mol⁻¹ Si. The simulation of PXRD data corresponding to intergrowths of different polymorphs was performed using DIFFaX.13

3. Results and discussion

3.1 Powder XRD

In our previous work we pointed to the similarity of the PXRD patterns of HPM-7 and the recently reported PKU-16.14 The PKU-16 topology, containing a 3D system of large (11 × 11 × 12) channels, has been assigned the Zeolite Framework Type code POS. 15 Attempts to Rietveld refine the structure of the asmade HPM-7 synthesized using the shorter 8BDMI dication

against synchrotron powder diffraction data were however not satisfactory (Fig. S1†). We note here that, unfortunately, the structure of HPM-7 is unstable under ambient air after calcination, being amorphized in a matter of hours. Since it was impossible to properly model and refine in GSAS the highly flexible dication, we used a rigid body SDA with the conformation and in the location determined to be more stable by molecular simulations. The refinement of that system worked relatively well but we noticed a large difficulty in modelling the peak shapes and peak broadenings. Furthermore, while we reached good residuals, we got a couple of too short bonds in spite of using soft bond restrains (T2-T3: 2.95 Å, T4-T4: 2.97 Å), and the Rietveld plot suggested that the model was very far from perfect (see red arrows in Fig. S1†); then, we were not able to reach convergence while refining all relevant parameters. While the observed problems may be possibly due to the difficulty in properly modelling the highly flexible dication, they also raised the question of the possible existence of disorder.

Because of the particular POS topology, we could envisage several possible sources of disorder based on intergrowths of closely related feasible polymorphs, by following two possible schemes:

- 1 simple intergrowths along the [110] and/or [1-10] directions, made possible by the presence of D4R in both directions, which define layers that could thus be exchanged without much strain.
- 2 intergrowths with new polymorphs deriving from POS by shifting the orientation of two different s4r units in the POS structure. POS and the new polymorphs could be intergrown along the [001] direction or, in a way similar to the option right above, along the [110] and [1-10] directions through the D4R rings in the structure.

The first possibility is based on the fact that in POS there is a central structural motif that is connected to itself through D4R units along the three crystallographic directions, with or without rotation of the unit along [001]. Thus, in addition to the POS topology (that we shall call here the polymorph POS-A), two different ordered and simple polymorphs (POS-B and POS-C, see Fig. 2) can be constructed and, based on them, intergrowths could occur along [110] and/or [1-10] of the POS structure. The unit cell size and energies of the three pure silica polymorphs fully refined by DFT are given in Table 1. Interestingly, the DFT calculated energies of the three polymorphs are very close to each other. Given their similar stability and the fact that the three polymorphs are built by the same structural unit connected through D4R, we anticipated that their intergrowths could be an important source of disorder.

We simulated the effect of stacking faults along one direction using DIFFaX. 13 For DIFFaX, we constructed a layer normal to the intergrowth direction (Fig. 2, bottom left) which can be stacked with a 0.5 cell shift normal to that direction to yield POS-A or without any shift to yield POS-B (Fig. 2, bottom right). Additionally, it is also possible to construct a smaller and simpler unit (half of the unit cell of the layer mentioned

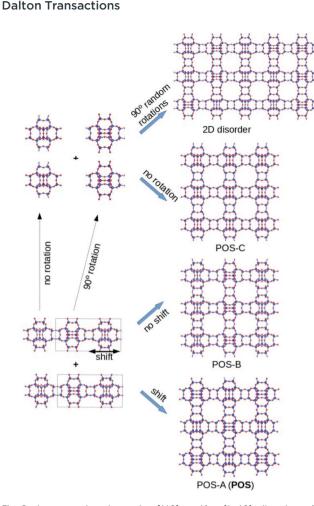


Fig. 2 Intergrowths along the [110] and/or [1-10] directions (here running vertically) of the POS topology. Bottom: a single layer (left) can be stacked with a shift of half of its unit cell to yield POS-A, or with no shift to yield POS-B. Top: a layer made using a half cell of the same layer can be used to build a third ordered polymorph when stacked with no rotations (POS-C), or to produce a 2D disordered material by randomly rotating the unit 90° along the normal to the page.

Table 1 Polymorphs directly derived from POS, with their relative DFT energies (R.E., relative to quartz) and the unit cell parameters upon geometry optimization

Polymorph	R.E. a	Space group	а	b	с
POS-A	2.98	$P4_2/mnm$ (136)	18.9537	18.9537	11.7623
POS-B	3.56	Pmmm (47)	11.7177	26.8892	13.3531
POS-C	2.93	Pmmm (47)	11.7915	12.7517	14.0098

^a Energy relative to quartz in kcal mol⁻¹ Si.

above) that can be intergrown with itself along [110], [1–10] or both with or without 90° rotations along c. Without rotations the polymorph POS-C arises, while POS-A and POS-B require alternate rotations along two or one directions respectively (Fig. 2). Stacking faults along a single direction can be simulated by DIFFaX, while disorder along two directions cannot. In Fig. 3, DIFFaX XRD simulations of intergrowths between

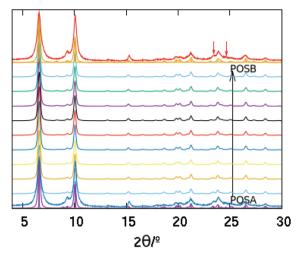


Fig. 3 Simulated XRD patterns of a series of structures obtained by intergrowing POS-A and POS-B along [1-10]. The bottom and top noiseless traces correspond to pure POS-A and POS-B, respectively. Two patterns are depicted for each one: those of the pure polymorphs calculated by VESTA (sharp patterns)¹⁶ and those of 99% pure polymorphs calculated by DIFFaX (broad patterns). The noisy patterns next to them (red and blue patterns) correspond both to the experimental HPM-7 pattern. The rest of the patterns correspond to the intergrowths of both polymorphs with 10% increase of POS-B from one to the next one. The red arrows point to the peaks more sensitive to the intergrowth, which suggest that HPM-7 is actually closer to the polymorph POS-A.

polymorphs POS-A and POS-B are shown. Interestingly, this kind of intergrowth has very little impact on the corresponding XRD patterns: most reflections are invariant and the reflections that do change have low relative intensity (see Fig. S2† with all the simulations superimposed). Furthermore, when the simple polymorph C is intergrown with itself with or without 90° rotations, again this results in very subtle changes in the corresponding XRD patterns (Fig. S3†). We thus conclude that, while HPM-7 is likely close to POS-A, it is very difficult to prove or disprove by powder XRD the existence of the described types of disorder in HPM-7 and related materials.

Additionally, as mentioned above, there can be another source of disorder in HPM-7, as shown in Fig. 4. There are two single 4MR (s4r) in the POS structure that could conceivably change in orientation while maintaining the rest of the topology intact. One is on the ab face of the unit cell and lies on that face in POS-A (s4r-a, below), the other is centred at the center of the unit cell and is normal to the [110] diagonal in POS-A (s4r-b). Four different polymorphs, in addition to POS-A, may arise by changing the orientation of these s4r (Table 2). When the orientation of s4r-a is taken out of the ab plane, the 11MR windows become 12MR windows. We note here that the polymorph that results when the orientation of both s4r is normal to [1-10] is the same as the one obtained orienting them normal to [110] (polymorph F). We have calculated by DFT the stabilities of these polymorphs and two of them are clearly more stable than the rest (Table 2): POS-A and

Fig. 4 Scheme showing all the possible orientations of the single 4 rings (s4r) derived from the POS topology. O atoms are omitted for clarity. The tetrahedral sites that are topologically invariant are depicted in blue. The s4r in the *ab* face can be oriented normal to [001] (like in POS-A and -D, bronze), [110] (POS-F and -G, green) or [1–10] (POS-E, black). The s4r in the center of the unit cell can be normal to [110] (POS-A, -E, -F, red) or [1–10] (POS-D and -G, yellow).

Table 2 Polymorphs derived from POS by altering the orientation of two single four membered rings

Polymorph	S4r-a ^a	S4r-b ^b	Pores	$R.E.^c$	Space group	$a = b^d$	c^d
POS-A	<u> </u>	<u> </u>	12 × 11 × 11	2.98	P4 ₂ /mnm (136)	18.9537	11.7623
POS-D	⊥[001]	1-10	$12 \times 11 \times 11$	5.71	$P4_{2}/mnm\ (136)$	18.7893	11.7580
$POS-E^e$	$\frac{1}{1}[1-10]$	<u> </u>	$12 \times 12 \times 12$	3.12	$P4_2/mmc~(131)$	12.7768^{f}	13.2879
POS-F	 110]	اً 110	$12 \times 12 \times 12$	6.59	$P4_2/mnm(136)$	18.0255	13.0923
POS-G	\perp [110]	$\frac{1}{1}[1-10]$	$12\times12\times12$	13.65	$P4_2/mnm~(136)$	18.3279	12.3685

^a Single 4 ring at the *ab* face. ^b Single 4 ring at the unit cell center. ^c Energy relative to quartz in kcal mol⁻¹ Si. ^d Unit cell parameters of the DFT geometry-optimized pure-silica polymorphs. ^e This polymorph is actually BEC. ^f The *a* cell edge of this polymorph is roughly half the diagonal of the *ab* face of the others.

the polymorph POS-E, which turned out to be BEC, the polymorph C of the Beta family. Two additional polymorphs (D and F) have higher relative energies while another one, polymorph G, is by far less stable than the rest. The structural relationship between POS and BEC was already noted by Hua $et\ al.^{14}$ These two polymorphs can be intergrown in two ways: along z, by sharing O and Si atoms at z=0 or along [110] or [1–10], due to the existence of equally spaced D4R in both polymorphs, in a similar way as described above for polymorphs A, B and C.

However, since there are large changes in the unit cell dimensions of polymorphs A and E (particularly along c, Table 2), the first type of intergrowth cannot be simulated by DIFFaX, while the second one would be in our opinion prevented by the large misfit along the [001] direction. Thus, this kind of possible disorder was not considered any further.

Fig. 5 shows the SEM images of the as-made HPM-7 synthesized with 8BDMI, (Fig. 5a and b) and 10BDMI (Fig. 5c and d). Both samples exhibit similar rod-like morphologies with a crystal length around 1 to 2 μ m, while the former shows aggregated crystal sticks in contrast to the latter with isolated and straight ones. High-resolution SEM data, Fig. 5d, allowed the observation of isolated HPM-7 crystallites and visualize the {001} facets presenting four-fold symmetry, marked by white circles.

3.2 3D-EDT

The already presented SEM observation (Fig. 5d) allowed deducing the tetragonal crystal system. Three dimensional electron

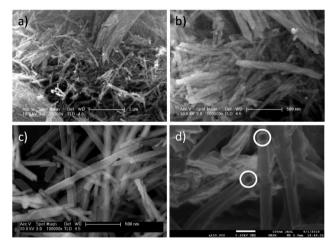


Fig. 5 SEM images of the as-made HPM-7 synthesized with 8BDMI (a and b), and 10BDMI (c and d). In figure (d) it is possible to appreciate the 4-fold symmetry of the material as indicated by the white circles.

diffraction tomography (3D-EDT) was used to collect and process the 3D electron diffraction data for structure solution. For 3D-EDT, the main zone axes were avoided during the data collection to reduce the strong dynamic scattering effect from Bragg reflection. The reciprocal lattice obtained confirmed a tetragonal unit cell with lattice constants: a = 19.385 Å, b = 19.385 Å, c = 11.898 Å, $\alpha = 89.999^{\circ}$, $\beta = 90.734^{\circ}$, $\gamma = 90.043^{\circ}$ obtained after analyzing 29 different crystallites. The space

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group was determined to be P42/mnm based on the reflection conditions (see Fig. S4 and Table S1†) and from the Fourier diffractogram (FD) analysis obtained from the atomic-resolution images (shown later on). To explore the possibility of any deviation from the aforementioned POS, 29 sets of 3D-EDT data were collected from 29 different particles. Each dataset was collected with a total rotation angle of 120°. Data solutions, unit cell parameters and other possible space group candidates are listed in Table S1.† We conclude that every crystal could be solved as P42/mnm in agreement with the POS topology. Although 3D-EDT allows the analysis of nanocrystals or very small domains in larger particles, limited by the size of the selected area diffraction aperture (SAED), it is still obtained by averaging several unit cells. To obtain more local information of smaller domains or the observation of structural defects at the atomic level, high-resolution imaging is required.18

3.3 C_s -corrected HRSTEM

Electron microscopy observations of HPM-7 were performed by means of C_s -corrected STEM-ADF combined with C_s -corrected STEM-ABF. Low magnification analysis was carried out together with atomic-resolution observations in order to extract the maximum degree of information of the materials. Fig. 6a corresponds to the C_s-corrected STEM-ADF low-magnification micrograph where different crystals are visualized. The length of these particles can normally reach up to 1 µm, while the width oscillated from 10 nm up to 100 nm.

A magnified region is depicted in Fig. 6b displaying the pore arrangement for this material. The Fourier Diffractogram

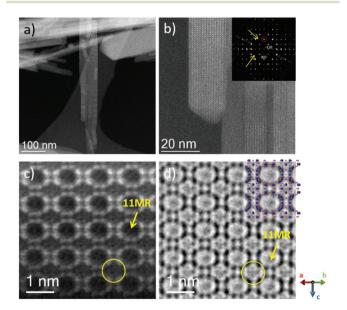


Fig. 6 C_s-corrected STEM analysis of HPM-7. (a) Low magnification ADF image of several crystals. (b) Closer observation that allows the identification of the pores. The FD is shown in the inset with arrows pointing to systematic extinctions. (c) and (d) Atomic resolution data using an ADF and an ABF detector, respectively, where the 11MR and the s4r are marked with an arrow and circle, respectively.

(FD) is shown in the inset and it can be indexed assuming P42/ mnm symmetry on the [110] orientation. From here, the clattice constant can be directly inferred by measuring the d-spacing of the (00-2) spot, pointed by a red circle, resulting to be 11.75 Å, in agreement with the data reported in the first two rows of Table 2 and from the 3D-EDT evaluation. Furthermore, the analysis of the Fourier diffractogram also displays some clear systematic extinctions (yellow arrows) of the crystal that corroborates the P42/mnm symmetry of HPM-7. The atomic resolution C_s -corrected STEM-ADF is depicted in Fig. 6c, where atomic columns appear as bright spots and the pores appear in dark. Despite the excellent data obtained using the ADF detector the observation of the s4r, perpendicular to each other and enclosed between the 11MR, denoted by a yellow arrow, is not clearly discernible (yellow circle). With the intention of increasing the degree of detail in the image, we turned into ABF data. This mode is particularly interesting for light elements as it collects more electrons to form the image in comparison with the ADF detector due to the smaller scattered angle. 19 Fig. 6d shows the corresponding ABF image of the same region of the same crystal. Here, in addition to the 11MR that was already visualized by ADF, a faint signal that would correspond to the s4r, marked by a yellow circle, is also distinguished.

Symmetry averaged data treatment together with image simulations was performed with the intention of corroborating if the experimental data matched that obtained from the POS framework type (simulated). Fig. 7 shows the averaged data assuming plane group symmetry p1, i.e. with no symmetry restrictions imposed (Fig. 7a). Additionally, the p2mm plane group symmetry that would correspond to the space group $P4_2/mnm$ on the [110] orientation is shown in Fig. 7b together with the ABF simulated image (without a template) for a material with a thickness of 11 nm, Fig. 7c. Additional image simulations were performed over polymorphs, B, C and D, see Fig. 8, along the [110] orientation. From a direct comparison of these images, it is possible to appreciate the significant differences between the experimental results and the suggested C and D models, while along this projection B cannot be differentiated from A. With the intention of obtaining additional information along a different zone axis the sample was embedded in a resin and ultramicrotomed. Fig. S5a \dagger shows the C_s -corrected STEM-ADF image at low magnification along the [001] orientation observing a clear differ-

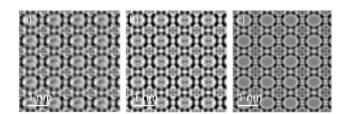


Fig. 7 C_s-corrected STEM-ABF analysis. (a) Symmetry averaged micrograph, p1. (b) Symmetry averaged micrograph, p2mm and (c) ABF simulated data of the POS framework for a sample thickness of 11 nm.

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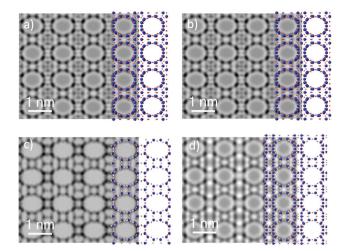


Fig. 8 ABF simulated data for the four polymorphs proposed. (a) POS-A, (b) POS-B, (c) POS-C and (d) POS-D. In every case the model along the same zone axis has been superimposed, with T atoms in blue and O in red. The sample thickness used was 11 nm.

ence when it is compared with the previous data. In this case, a squared-liked morphology is observed, the size of this particle is around 80 nm and the electron diffraction pattern confirms the four-fold axes (Fig. S5b†). The unit cell parameters from this projection are a = b = 18.52 Å assuming the $P4_2/mnm$ symmetry. A closer look displaying the pore arrangement appears in Fig. S5c and d,† allowing to conclude that the predominant phase was POS.

PXRD analyses combined with 3D-EDT data and the atomic resolution observations allowed to safely assume that HPM-7 presents the P42/mnm space group symmetry confirming the predominant POS framework type. Nevertheless, the misfitting in the PXRD analysis and the possible existence of other feasible polymorphs urged us to investigate the issue further. Several crystallites were inspected in order to find the possible deviations from the accepted symmetry. Fig. 9a shows the C_s corrected STEM-ABF data of another HPM-7 crystal on the [110] orientation. Clearly, significant differences with the images presented before can be observed. The FDs (Fig. 9b) have been extracted from the two different regions marked by red and yellow dashed squares in Fig. 9a. The FD of the red

dashed area exhibits additional extra spots, not for the shorter q values but for the longest reciprocal distances; from the [3-30] and higher, additional diffraction spots were observed, marked by circles, also observed along the c axis (white oval). The second FD presented here corresponds to the region marked by a yellow dashed square, which is in good agreement with the previous POS framework shown. A closer look at both regions is presented in Fig. 9c and d. Fig. 9d is in agreement with POS; however, Fig. 9c is significantly different. By direct comparison with the 4 models presented in Fig. 8, there is a much closer relationship with POS-D. The POS-D simulated image has been superimposed in Fig. 9c, bottom right. Additionally, a small framework modulation along the ab axis can be appreciated, which displaces the framework by ≈ 1 Å, as marked by a red line. Since it occurs in small regions it may be difficult to notice by both XRD and 3D-EDT measurements.

Several of the polymorphs closely related to POS (BEC, POS-B and, specially, POS-C) have energies similar (or even smaller in the case of POS-C) to those of POS-A (Tables 1 and 2) and all have very similar pore systems. The fact that, however, they do not have a large presence in HPM-7 suggests an effective structure-direction during the synthesis. Although our energy calculations correspond to the pure silica polymorphs, the effect of Ge is known to generally favour structures with D4R. Since all the polymorphs discussed here have the same density of D4R, the organic dications are deemed as effective structure-direction agents able to prevent the extensive formation of polymorphs other than POS-A.

Conclusions

HPM-7 is isostructural to POS in view of the HRSTEM and 3D-EDT data, although disorder may exist and may be very difficult to distinguish by PXRD, as indicated by DIFFaX simulations. Three ordered polymorphs with a 3D system of 12×11 \times 11 pores (POS-A), 12 \times 11 \times 10 (POS-B) and 12 \times 12 \times 10 (POS-C), able to intergrow with each other and all with very similar energies, have been identified. Additionally, four structurally related structures (POS-D to POS-G, one with 12 \times 11 \times 11 pores and the rest, including BEC, with $12 \times 12 \times 12$ pores) can be derived from POS. While HPM-7 basically possesses the

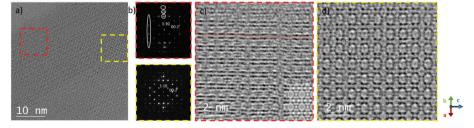


Fig. 9 C_s-STEM ABF observation of HPM-7 along the [110] projection. (a) Low-magnification micrograph, the two areas of analysis are marked by dashed squares. (b) FDs obtained from the two different regions and indexed assuming POS. (c) High-resolution image of the red square. The simulated POS-D is shown in the inset. The observed modulation is followed by a red line. (d) High-resolution of the region marked by the yellow square, which is in agreement with POS.

POS-A (*i.e.*, POS) structural type, a deeper analysis performed on different crystallites corroborates the occasional occurrence of structural defects compatible with the POS-D polymorph. The apparent scarcity of the presence of polymorphs other than POS-A, despite their very similar energy, structural units and pore systems, suggests that the organic dication is able to effectively suppress their appearance.

Conflicts of interest

There are no conflicts to declare.

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